

Features

- High Density Cell Design for Ultra Low R_{DS(on)}
- Fully Characterized Avalanche Voltage and Current
- · Excellent Package for Good Heat Dissipation
- · Special Process Technology for High ESD Capability
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

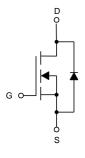
Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Volltage	V _{GS}	±20	V
Continuous Drain Current	I _D	20	Α
Pulsed Drain Current	I _{DM}	60	Α
Single Pulse Avalanche Energy (Note 1)	E _{AS}	72	mJ

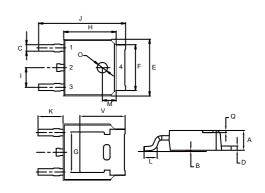
Note: $1.V_{DD}=30V$, L=0.5mH, $R_{G}=25\Omega$, $Starting T_{J}=25$ °C.

Internal Structure



N-CHANNEL MOSFET

DPAK(TO-252)



- 1. Gate
- 2,4. Drain
- 3. Source

DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.087	0.094	2.20	2.40		
В	0.000	0.005	0.00	0.13		
С	0.026	0.034	0.66	0.86		
D	0.018	0.023	0.46	0.58		
Е	0.256	0.264	6.50	6.70		
F	0.201	0.215	5.10	5.46		
G	0.190		4.83		TYP.	
Н	0.236	0.244	6.00	6.20		
ı	0.086	0.094	2.18	2.39		
J	0.386	0.409	9.80	10.40		
K	0.114		2.90		TYP.	
L	0.055	0.067	1.40	1.70		
M	0.063		1.60		TYP.	
0	0.043	0.051	1.10	1.30		
Q	0.000	0.012	0.00	0.30		
V	0.211		5.3	35	TYP.	



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

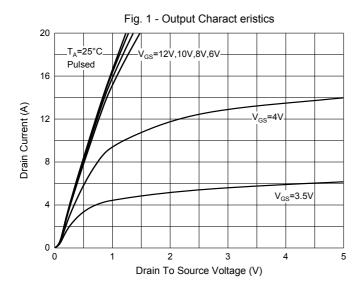
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics	1			•	1	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	60			V
Gate-Source Leakage Current	I _{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μΑ
Gate-Threshold Voltage ^(Note 2)	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1	2	3	V
Drain-Source On-Resistance ^(Note 2)	R _{DS(on)}	V _{GS} =10V, I _D =20A		37	45	mΩ
Dynamic Characteristics(Note 3)				•	•	
Input Capacitance	C _{iss}			500		
Output Capacitance	C _{oss}	V _{DS} =30V,V _{GS} =0V,f=1MHz		60		pF
Reverse Transfer Capacitance	C _{rss}			25		
Total Gate Charge	Q _g			12		
Gate-Source Charge	Q_{gs}	V _{DS} =48V,V _{GS} =10V,I _D =15A		4.1		nC
Gate-Drain Charge	Q_{gd}			4.5		
Turn-On Delay Time	t _{d(on)}			5		
Turn-On Rise Time	t _r	V_{DD} =30V, R _G =3 Ω , I _D =2A,		2.6		
Turn-Off Delay Time	t _{d(off)}	V _{GS} =10V		16.1		ns
Turn-Off Fall Time	t _f			2.3		
Drain-Source Body Diode Cha	racteristi	cs				
Continuous Body Diode Current	Is				20	۸
Pulsed Diode Forward Current	I _{SM}				60	Α
Body Diode Voltage	V _{SD}	I _S =20A, V _{GS} =0V			1.2	V

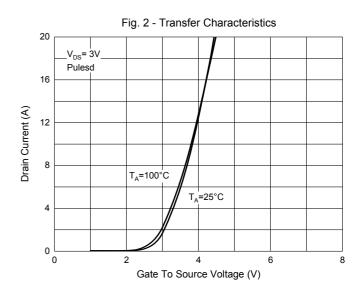
Note 2. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤2%.

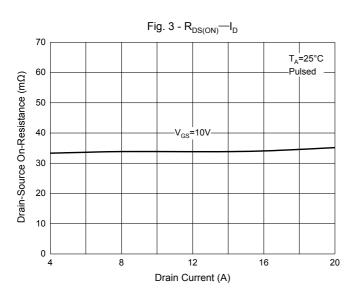
^{3.} Guaranteed by Design, Not Subject to Production Testing.

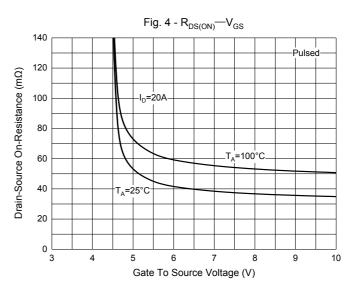


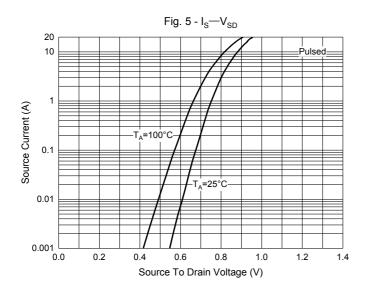
Curve Characteristics

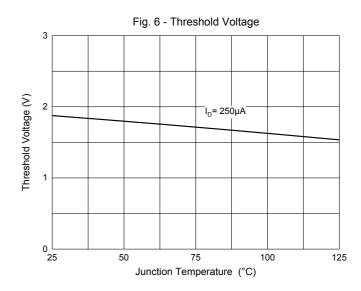














Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel	

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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